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Nitrogen Dioxide Gas Sensor Based on Monolayer SnS: A First-principles Study

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Abstract—The sensing behavior of monolayer SnS for four gas molecules (NH₃, NO₂, CO, and H₂O) are studied by first-principles calculation based on density-functional theory. We calculate adsorption energy, adsorption distance, and hirshfeld charge to estimate the adsorption ability of monolayer SnS for these gases. The results demonstrate that all the gas molecules show physisorption nature. We further calculate the current-voltage (I-V) curves using the nonequilibrium Green's function (NEGF) formalism for evaluating the NO₂ gas sensing properties. The monolayer SnS is found to be strongly sensitive to NO₂ molecule dependent on moderate adsorption energy, excellent charge transfer, and significant change of I-V property before and after gas adsorption. Therefore, we suggest that monolayer SnS can be a prominent candidate for application as NO₂ gas sensor.

Index Terms—Density-functional theory, monolayer SnS, nitrogen dioxide, gas sensor.

I. INTRODUCTION

S ENSING gas molecules, especially toxic gas, is critical in environmental pollution monitoring, agricultural, and medical applications [1]. NO₂ is recognized as an air pollutant and has been released during many types of fuel combustions. Moreover, NO₂ plays an important role in producing acid rain [2], which does great harm to both human and environment. Great efforts have been made in the development of NO₂ sensors as a safety precaution device [3, 4]. However, some available NO₂ sensors based on metal oxides usually show either poor selectivity or high operation temperature [5, 6]. Therefore, it is in great need of NO₂ gas sensors with considering sensitivity, selectivity, and low-cost.

Two-dimensional (2D) materials have great potential for gas sensors [7, 8] owing to their rapid response and the associated charge transfer between gas molecules and the substrates. Due to the enhanced surface to volume ratio, 2D transition metal dichalcogenides (TMDCs) and transition metal oxides (TMOs) are becoming more prevalent in gas sensing [9, 10]. Wang *et al.* have concluded that only binary TMOs and post-transition metal oxides find their gas sensor application [11]. However, few work has been done on post-TMDC for gas sensor. Recently, a new binary monochalcogenide layered material, tin sulfide (SnS) with topological superconductivity, excellent electronic and optical properties, a potential earth-abundant photovoltaic (PV) material, has been attracted increasing attention for application in photodetector [12] and energy storage [13], etc. Some theoretical studies have reported on the electronic properties of single-layer or multi-layer SnS [14]. The properties of monolayer and few layer SnS are different, such as the optoelectronic properties of the material vary significantly with respect to the number of layers and the band gap is wider for fewer layers. Despite these interesting studies, the sensing behavior of SnS for small molecules, such as NH₃, NO₂, CO and H₂O, is still lacking. In this letter, we investigate the effect of gas adsorption on monolayer SnS in a systematic understanding. And our work confirms the SnS has dramatic performance in gas sensing.

II. THEORY AND SIMULATIONS

First-principles calculations are performed using the DMol³ package based on density-functional theory (DFT). The exchange correlation interaction is treated by generalized gradient approximation (GGA) with Perdew-Burke-Ernzerh (PBE) functional [15, 16]. We use Grimme [17] custom method for DFT-D to describe tiny van der Waals interaction. The Brillouin zone integration is sampled by 8×8×1 k-grid mesh for a 3×3 supercell (36 atoms) model. Periodic boundary conditions are applied in the x- and y- directions. The vacuum space is set as 20 Å to reduce interaction of the adjacent layers in the zdirection. All of the atomic positions are optimized until the maximum force is less than 0.002 Ha/Å. In order to characterize the adsorption strength between gas molecules and monolayer SnS, the adsorption energy (E_{ad}) defined as $E_{ad}=E_{SnS+gas}-E_{SnS-gas}$ E_{gas} , where $E_{\text{SnS+gas}}$, E_{SnS} , and E_{gas} represent the total energy of SnS-gas adsorption system, pristine SnS sheet, and free gas molecules, respectively. The electron localization function (ELF) is calculated by CASTEP code. The electronic transport properties are investigated by the nonequilibrium Green's function (NEGF) formalism [18] within the Atomistix ToolKit

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(ATK) package. The electric current through the contact region is calculated by the following formula:

$$I(V_b) = G_0 \int_{\mu_L}^{\mu_R} T(E, V_b) \, dE$$
 (1)

where V_b is the bias voltage, $G_0 = 2e^2h^{-1}$ is the unit of quantum conductance, μ_L and μ_R are the chemical potentials of left and right electrodes and $T(E, V_b)$ represents the bias-dependent transmission coefficient.

III. RESULTS AND DISCUSSION

To understand the sensing behaviour of monolayer SnS for gas molecules (NH₃, NO₂, CO and H₂O), we calculate different adsorption configurations. The most stable adsorption configurations for NH₃ and NO₂ molecule are shown in Fig. 1. More detailed information from the simulation of different molecule-SnS systems, including adsorption energies (E_{ad}) , equilibrium distances (d), and Hirshfeld charge (Q) are listed in Table 1. The d is the shortest distance between the atoms of monolayer SnS and molecule. The negative sign of Q indicates charge transfers from SnS to molecule. The E_{ad} of -0.438 eV is calculated for NH₃ adsorption on monolayer SnS (Fig. 1a) associated with the d of 2.76 Å that is larger than the sum of the covalent radii of N and Sn atoms (2.11 Å)[19], indicating physisorption interaction nature. In the case of NO₂, the most stable adsorption configuration is shown in Fig. 1b. This structure has the E_{ad} of -0.9 eV and the separation distance of 2.47 Å. Because NO_2 is a paramagnetic molecule, the adsorption introduces stronger doping and produces larger E_{ad} . The E_{ad} value is significantly larger than that of NO₂ adsorption on phosphorene (0.5 eV)[20], indicating a higher level detection sensitivity can be achieved using SnS based sensors compared to phosphorene. The adsorption of CO and H₂O on monolayer SnS produces weaker binding energies (-0.190 eV and -0.388 eV) with smaller value of charge transfer (-0.006 eV and -0.055 eV), indicating that SnS is unpromising sensing material of gas sensors to detect the two molecules.



Fig.1. The most stable configuration for (a) NH_3 and (b) NO_2 on monolayer SnS. (The yellow and gray balls represent S and Sn atoms, where blue, white and red represent N,H and O atoms, respectively).

TABLE 1	
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THE ADSORPTION ENERGY, ADSORPTION DISTANCE AND HIRSHFELD CHARGE OF DIFFERENT GAS ON TIN SULFIDE

gas	$E_{ad}(eV)$	$d(\dot{A})$	<i>Q</i> (e)
NH ₃	-0.439	2.76	0.085
NO_2	-0.900	2.47	-0.307

СО	-0.190	3.29	-0.006
H ₂ O	-0.388	2.72	-0.055
(a)		(b)	
		(d)	

Fig. 2. The CDD for (a) NH₃ and (b) NO₂ adsorbed on monolayer SnS. The isosurface is taken as 0.003 e Å⁻³. (c) and (d) are the corresponding ELF plots.

To further explore the interaction between gas molecule and SnS, the charge density difference (CDD) are presented in Fig. 2. The blue and yellow regions show charge accumulation and depletion, respectively. The CDD for NH₃/SnS system shows that the charge is depleted on NH₃ molecule (Fig. 2a) and charge accumulated on SnS surface. As a result, NH3 acts as a charge donor and provides 0.085 e to monolayer SnS. In the case of NO2 (Fig. 2b), most charge accumulated on NO2 molecule surface, while charge depleted on top surface of SnS. The results reveal that NO₂ acts as charge acceptor with larger charge transfer (-0.307 e) because the spin-induced magnetic moment leads to a strong doping. Moreover, the grade of ELF is encoded using a color scheme in which high values correspond to orange and low values to blue. The ELF plot clearly shows that there is no electron sharing between gas molecules (NH₃ and NO₂) and SnS, which proves powerfully the interaction is physical adsorption.



Fig. 3. The total DOS and PDOS for (a) NH_3 and (b) NO_2 adsorbed on monolayer SnS. The Fermi level is set to zero.

The density of states (DOS) and PDOS profiles are presented in Fig. 3. The total DOS of NH₃/SnS system (Fig. 3a) does not change much compared with the pristine SnS, indicating that the outstanding electronic properties of SnS stay unaffected after adsorption. It is find that there is no phenomenon of orbital hybridization in the NH₃/SnS structure. The contribution of NH₃ electronic level to the total DOS is localized between -4 eV to -2 eV in the valence band, which is far away from the Fermi level. For the NO₂ on monolayer SnS (Fig. 3b), the strong interaction causes a dramatic change of the DOS on both sides near the Fermi level. Besides, the Sn s and O p orbitals of the NO₂/SnS system share the similar states just above the Fermi level, indicating the strong orbital hybridization. The change of DOS, is expected to bring about obvious changes in the corresponding electronic properties of the SnS.



Fig.4. I-V characteristic curves of pristine SnS and NO2 on SnS.

To observing clearly the conductivity modification, we calculate current-voltage (I-V) curves with and without NO₂ adsorption. The simulated I-V curves are plotted in Fig. 4. We find that it is almost no current when bias varies from 0 to 1.8 V due to the existence of band gap. When bias over 1.8 V, the current strats to increase dramatically. Under the bias of 3.0 V, the current passing through the pure SnS is 1.82 μ A, while the current of SnS with the NO₂ adsorption under the same bias is increased to 5.25 μ A, which is higher than that of silicon carbide nanotube [21] and carbon nanotube [22]. The DOS of SnS without and with NO₂ molecule adsorption is similar in the energy range of 1.8 to 3 eV. Nevertheless, the conductivity of SnS with NO₂ molecule is higher than that of pristine SnS. Because the charge transfer from SnS to NO₂ molecule, which is equivalent to hole doping for SnS and enhance its conductivity. Thus, SnS can be an excellent sensing material to detect NO₂.

IV. CONCLUSION

In summary, we systemically study the sensing behavior of monolayer SnS for gas molecules (NH₃, NO₂, CO, and H₂O) by using the first-principles calculation, and find the following interesting phenomenon: (1) NO₂ adsorption is a physisorption on monolayer SnS as compared with other gas molecules with the largest adsorption energy (-0.9 eV) and moderate charge transfer (-0.307 *e*), which is suitable for adsorption/desorption of gas molecules on/from SnS surface. Therefore, the excellent reversibility of gas sensor based on SnS is obtained. (2) The

transport calculations indicate that NO_2 molecule adsorption on monolayer SnS increase the current, thus changing the resistance, which can be directly measured experimentally. Such sensitivity and selectivity for NO_2 molecule make SnS as a good candidate of a superior NO_2 gas sensor.

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